

FEATURES

Access time: 55 nsLow power consumption:

Operating current: 30/20mA (TYP.) Standby current: 4 µA (TYP.) C-version

■ Single $2.7V \sim 5.5V$ power supply

■ Fully Compatible with all Competitors 5V product

■ Fully Compatible with all Competitors 3.3V product

■ Fully static operation

■ Tri-state output

Coming

Soon!

■ Data retention voltage : 2.0V (MIN.)

All products ROHS Compliant

■ Package 32-pin 450 mil SOP

32-pin 8mm x 20mm TSOP-I

32-pin 600 mil P-DIP

32-pin 8mm x 13.4mm sTSOP

*36-ball 6mm x 8mm TFBGA

*44-pin 8mm x 20mm TSOP-II

GENERAL DESCRIPTION

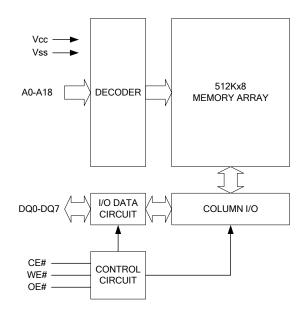
The AS6C4008 is a 4,194,304-bit low power CMOS static random access memory organized as 524,288 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

The AS6C4008 is well designed for very low power system applications, and particularly well suited for battery back-up non-volatile memory application.

The AS6C4008 operates from a single power supply of $2.7V \sim 5.5V$

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FUNCTIONAL BLOCK DIAGRAM

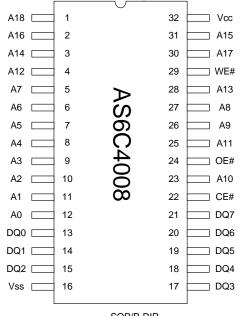


PIN DESCRIPTION**

SYMBOL	DESCRIPTION
A0 - A18	Address Inputs
DQ0 – DQ7	Data Inputs/Outputs
CE#	Chip Enable Inputs
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground
NC	No Connection

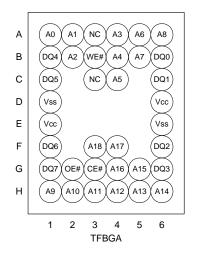


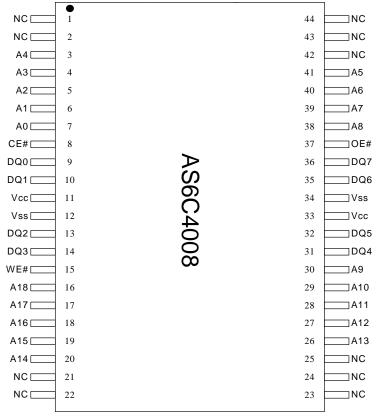
PIN CONFIGURATION





SOP/P-DIP







ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Terminal Voltage with Respect to Vss	VTERM	-0.5 to 6.5	V
		0 to 70(C grade)	
Operating Temperature	TA		°C
		-40 to 85(I grade)	
Storage Temperature	Тѕтс	-65 to 150	°C
Power Dissipation	PD	1	W
DC Output Current	Іоит	50	mA
Soldering Temperature (under 10 sec)	TSOLDER	260	°C

^{*}Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	Н	Х	Х	High-Z	I _{SB1}
Output Disable	L	Н	Н	High-Z	Icc,Icc1
Read	L	L	Н	Dout	Icc,Icc1
Write	L	Х	L	Din	Icc,Icc1

Note: $H = V_{IH}$, $L = V_{IL}$, X = Don't care.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		MIN.	TYP. *3	MAX.	UNIT
Supply Voltage	Vcc			2.7	3.0	5.5	V
Input High Voltage	V _{IH} *1			0.7* Vcc	-	Vcc+0.3	V
Input Low Voltage	V _{IL} *1			- 0.2	-	0.6	V
Input Leakage Current	ILI	$V_{CC} \ge V_{IN} \ge V_{SS}$		- 1	-	1	μΑ
Output Leakage Current	ILO	$V_{CC} \ge V_{OUT} \ge V_{SS},$ Output Disabled		- 1	-	1	μA
Output High Voltage	Vон	Iон = -1mA	2.4	-	-	V	
Output Low Voltage	Vol	IoL = 2mA		-	-	0.4	V
	Icc	Cycle time = Min. $CE\# = 0.2V$, $I_{I/O} = 0mA$	- 55	-	30	60	mA
Average Operating		other pins at 0.2V or Vcc - 0.2V	,				
Power supply Current	Icc1	Cycle time = 1μ s CE# = 0.2V, $I_{I/O}$ = 0mA other pins at 0.2V or V_{CC} - 0.2V	/	-	4	10	mA
Standby Power Supply Current	I _{SB1}	$CE\# \ge Vcc - 0.2V \qquad \qquad \frac{^*C}{^*I}$		-	4	50 ^{*4} 50 ^{*4}	μA μA

Notes: 1. VIH(max) = Vcc + 3.0V for pulse width less than 10ns. VIL(min) = Vss - 3.0V for pulse width less than 10ns.

^{2.} Over/Undershoot specifications are characterized, not 100% tested.

^{3.} Typical values are included for reference only and are not guaranteed or tested.

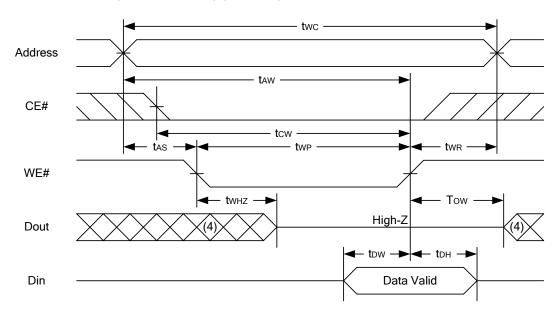
Typical valued are measured at Vcc = Vcc(TYP.) and TA = 25°C

^{4. 25}µA for special request

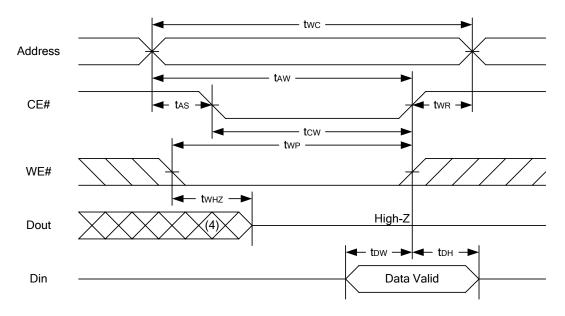
^{*}C=Commercial temperature/I = Industrial temperature



WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



WRITE CYCLE 2 (CE# Controlled) (1,2,5,6)



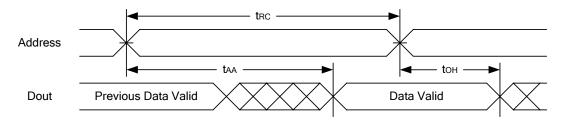
Notes

- 1.WE#, CE# must be high during all address transitions.
- 2.A write occurs during the overlap of a low CE#, low WE#.
- 3.During a WE# controlled write cycle with OE# low, twp must be greater than twHz + tpw to allow the drivers to turn off and data to be placed on the bus.
- 4. During this period, I/O pins are in the output state, and input signals must not be applied.
- 5.If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
- 6.tow and twHz are specified with CL = 5pF. Transition is measured $\pm 500mV$ from steady state.

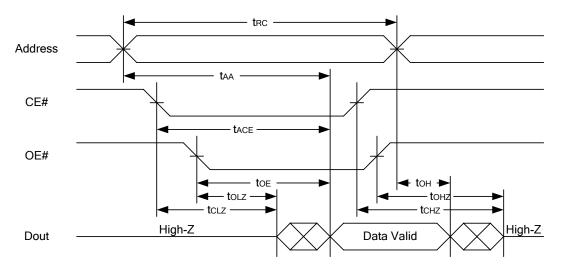


TIMING WAVEFORMS

READ CYCLE 1 (Address Controlled) (1,2)



READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)

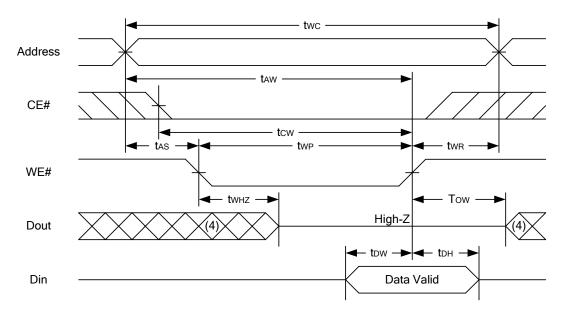


Notes:

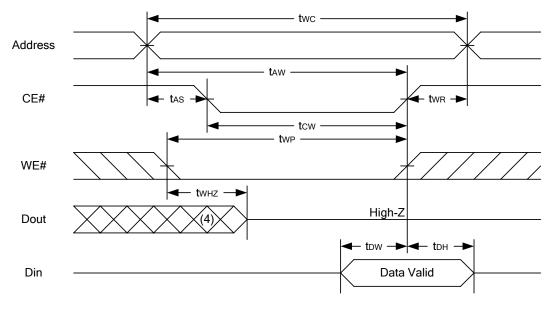
- 1.WE# is high for read cycle.
- 2.Device is continuously selected OE# = low, CE# = low.
- 3.Address must be valid prior to or coincident with CE# = low,; otherwise t_{AA} is the limiting parameter.
- 4.tclz, tolz, tchz and toHz are specified with CL = 5pF. Transition is measured ± 500 mV from steady state.
- 5.At any given temperature and voltage condition, t_{CHZ} is less than t_{CLZ} , t_{OHZ} is less than t_{OLZ} .



WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



WRITE CYCLE 2 (CE# Controlled) (1,2,5,6)



Notes

- 1.WE#, CE# must be high during all address transitions.
- 2.A write occurs during the overlap of a low CE#, low WE#.
- 3.During a WE# controlled write cycle with OE# low, twp must be greater than twHz + tpw to allow the drivers to turn off and data to be placed on the bus.
- 4. During this period, I/O pins are in the output state, and input signals must not be applied.
- 5.If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
- 6.tow and twHz are specified with CL = 5pF. Transition is measured $\pm 500mV$ from steady state.

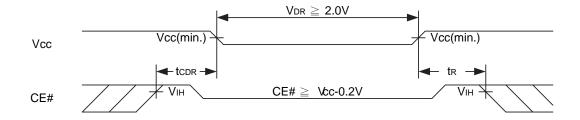


DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Vcc for Data Retention	V _{DR}	CE# ≥ Vcc - 0.2V	2.0	-	5.5	V
Data Retention Current	I _{DR}	Vcc = 2.0V **C	-	2	30	μ
		CE# ≧ Vcc - 0.2V **I	-	2	30	μΑ
Chip Disable to Data Retention Time	tcdr	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	tr		t RC∗	-	-	ns

trc* = Read Cycle Time **C=Commercial temperature/l=Industrial temperature

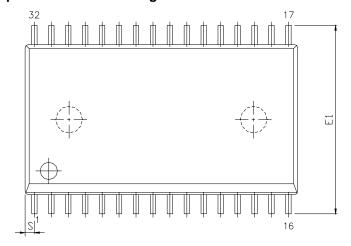
DATA RETENTION WAVEFORM

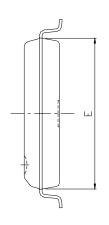


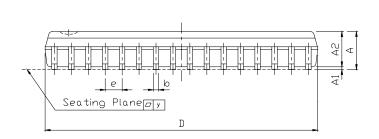


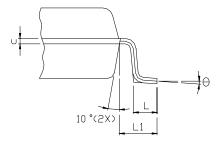
PACKAGE OUTLINE DIMENSION

32 pin 450 mil SOP Package Outline Dimension





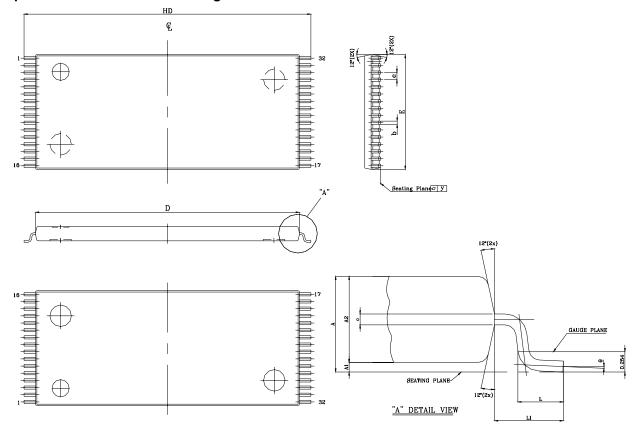




SYM. UNIT	INCH.(BASE)	MM(REF)
Α	0.118 (MAX)	2.997 (MAX)
A1	0.004(MIN)	0.102(MIN)
A2	0.111(MAX)	2.82(MAX)
b	0.016(TYP)	0.406(TYP)
С	0.008(TYP)	0.203(TYP)
D	0.817(MAX)	20.75(MAX)
E	0.445 ±0.005	11.303 ±0.127
E1	0.555 ±0.012	14.097 ±0.305
е	0.050(TYP)	1.270(TYP)
L	0.0347 ±0.008	0.881 ±0.203
L1	0.055 ±0.008	1.397 ±0.203
S	0.026(MAX)	0.660 (MAX)
у	0.004(MAX)	0.101(MAX)
Θ	0° -10°	0° -10°



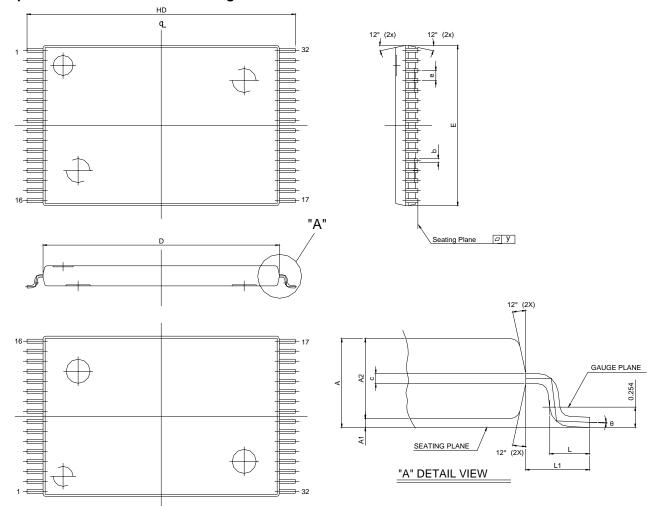
32 pin 8mm x 20mm TSOP-I Package Outline Dimension



SYM. UNIT	INCH(BASE)	MM(REF)
А	0.047 (MAX)	1.20 (MAX)
A1	0.004 ±0.002	0.10 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.008 + 0.002	0.20 + 0.05
	- 0.001	-0.03
С	0.005 (TYP)	0.127 (TYP)
D	0.724 ±0.004	18.40 ±0.10
Е	0.315 ±0.004	8.00 ±0.10
е	0.020 (TYP)	0.50 (TYP)
HD	0.787 ±0.008	20.00 ±0.20
L	0.0197 ±0.004	0.50 ±0.10
L1	0.0315 ±0.004	0.08 ±0.10
у	0.003 (MAX)	0.076 (MAX)
Θ	0°∼5°	0°∼5°



32 pin 8mm x 13.4mm sTSOP Package Outline Dimension

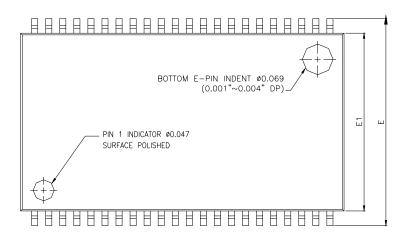


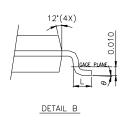
UNIT SYM.	INCH(BASE)	MM(REF)
Α	0.049 (MAX)	1.25 (MAX)
A1	0.005 ±0.002	0.130 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.008 ±0.01	0.20±0.025
С	0.005 (TYP)	0.127 (TYP)
D	0.465 ±0.004	11.80 ±0.10
E	0.315 ±0.004	8.00 ±0.10
е	0.020 (TYP)	0.50 (TYP)
HD	0.528±0.008	13.40 ±0.20.
L	0.0197 ±0.004	0.50 ±0.10
L1	0.0315 ±0.004	0.8 ±0.10
у	0.003 (MAX)	0.076 (MAX)
Θ	0°∼5°	0°∼5°

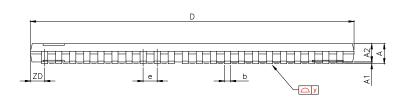


PACKAGE DIMENSIONS

44-pin 400mil TSOP-Ⅱ Package Outline Dimension





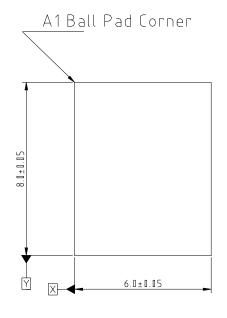


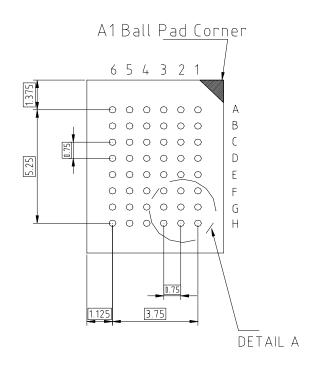


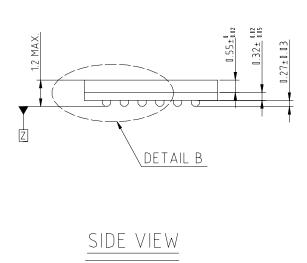
SYMBOLS	DIMENSI	ONS IN MILL	METERS	DIMENSIONS IN MILS		
STWIBOLS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	-	-	1.20	-	-	47.2
A1	0.05	0.10	0.15	2.0	3.9	5.9
A2	0.95	1.00	1.05	37.4	39.4	41.3
b	0.30	-	0.45	11.8	-	17.7
С	0.12	-	0.21	4.7	-	8.3
D	18.212	18.415	18.618	717	725	733
E	11.506	11.760	12.014	453	463	473
E1	9.957	10.160	10.363	392	400	408
е	-	0.800	-	-	31.5	-
L	0.40	0.50	0.60	15.7	19.7	23.6
ZD	-	0.805	-	-	31.7	-
У	-	-	0.076	-	-	3
θ	0°	3°	6°	0°	3°	6°

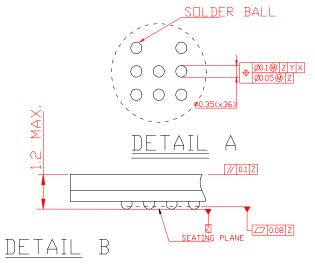


36 ball 6mm × 8mm TFBGA Package Outline Dimension



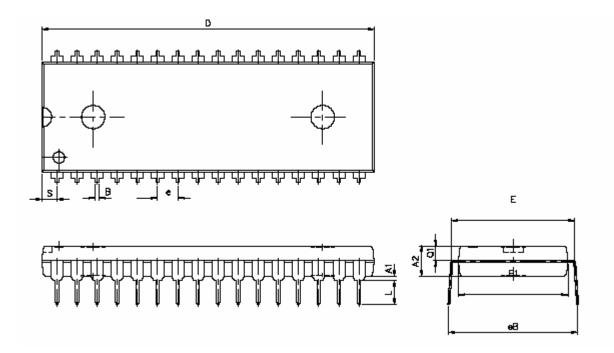








32 pin 600 mil P-DIP Package Outline Dimension



SYM. UNIT	INCH(BASE)	MM(REF)
A1	0.001 (MIN)	0.254 (MIN)
A2	0.150 ± 0.005	3.810 ± 0.127
В	0.018 ± 0.005	0.457 ± 0.127
D	1.650 ± 0.005	41.910 ± 0.127
Е	0.600 ± 0.010	15.240 ± 0.254
E1	0.544 ± 0.004	13.818 ± 0.102
е	0.100 (TYP)	2.540 (TYP)
eB	0.640 ± 0.020	16.256 ± 0.508.
L	0.130 ± 0.010	3.302 ± 0.254
S	0.075 ± 0.010	1.905 ± 0.254
Q1	0.070 ± 0.005	1.778 ± 0.127

Note: D/E1/S dimension do not include mold flash.



ORDERING INFORMATION

Ordering Codes

				Operating	Speed
Alliance	Organization	VCC range	Package	Temp	ns
AS6C4008-55PCN	512k x 8	2.7-5.5V	32pin 600mil PDIP	Commercial ~ 0° C to 70° C	55
AS6C4008-55SIN	512k x 8	2.7-5.5V	32pin 450mil SOP	Industrial ~ -40°C to 85° C	55
AS6C4008-55TIN	512k x 8	2.7-5.5V	32pin TSOP-I (8 x 20 mm)	Industrial ~ -40°C to 85° C	55
AS6C4008-55STIN	512k x 8	2.7-5.5V	32pin sTSOP (8 x 13.4 mm)	Industrial ~ -40°C to 85° C	55
AS6C4008-55ZIN	512k x 8	2.7-5.5V	32pin TSOP-II 400mil *	Industrial ~ -40°C to 85° C	55
AS6C4008-55BIN	512k x 8	2.7-5.5V	36pin TFBGA (6mm x 8mm)*	Industrial ~ -40°C to 85° C	55

*Coming Soon!

Part numbering system

AS6C	4008	- 55	X	X	N
			Package Options: P = 32 pin 600 mil P-DIP S = 32 pin 450 mil SOP	Tomporatura Pango	
			•	Temperature Range:	
low	Device		T = 32 pin TSOP-I (8mm x 20 mm)	C = Commercial	N = Lead
power	Number		ST = 32 pin sTSOP (8mm x 13.4 mm)	(0°C to +70° C)	Free ROHS
SRAM	40 = 4M	Access	Z =44 pin TSOP-II 400 mil*	I = Industrial	Compliant
prefix	<mark>08</mark> = by 8	Time	B = 36 pin TFBGA (6mm x 8mm)*	(-40° to +85° C)	Part

^{*} Coming Soon!

February 2007 AS6C4008





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